TOSHIBA Transistor Silicon PNP Triple Diffused Type

# 2SA1972

#### **High-Voltage Switching Applications**

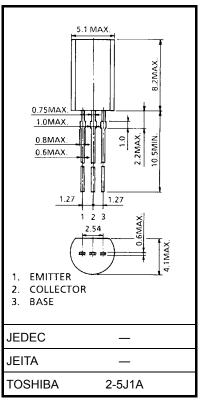
Unit: mm

• High breakdown voltage: VCEO = -400 V

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-400	V	
Collector-emitter voltage		V <sub>CEO</sub>	-400	V	
Emitter-base voltage		V <sub>EBO</sub>	-7	V	
Collector current	DC	IC	-0.5	Α	
	Pulse	ICP	-1		
Base current		ΙΒ	-0.25	Α	
Collector power dissipation		PC	900	mW	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 0.36 g (typ.)

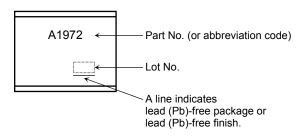
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



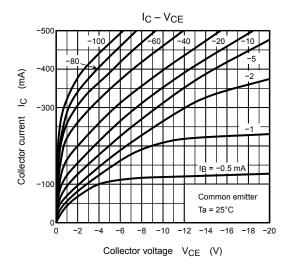
## Electrical Characteristics (Ta = 25°C)

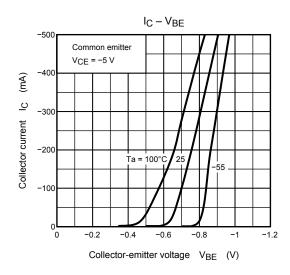
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = -400 V, I <sub>E</sub> = 0	_	_	-10	μΑ
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = -7 V, I <sub>C</sub> = 0	_	_	-1	μΑ
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-400	_	_	V
DC current gain		h <sub>FE (1)</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -20 \text{ mA}$	140	_	450	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -100 mA	140	_	400	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = -100 mA, I <sub>B</sub> = -10 mA	_	-0.4	-1.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = -100 mA, I <sub>B</sub> = -10 mA	_	-0.76	-0.9	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -50 mA	_	35	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	_	18	-	pF
Switching time Stor	Turn-on time	t <sub>on</sub>	Output  20 $\mu$ s Part No. $\leftarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$ $\downarrow$	_	0.2	_	
	Storage time	t <sub>stg</sub>		_	2.3	_	μs
	Fall time	t <sub>f</sub>		_	0.2		

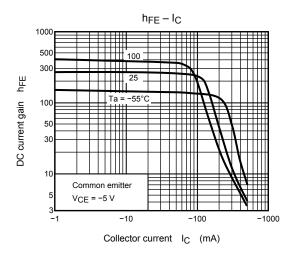
## Marking

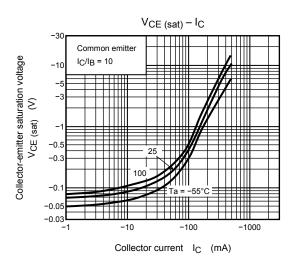


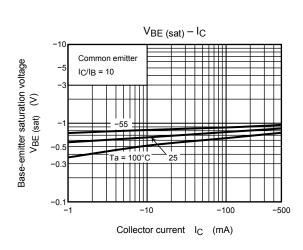
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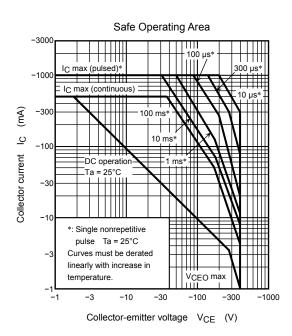












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